

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L2	108799	257/\$.ccls. substrate with insulat\$3 with conductive with semi\$1conductor	USPAT	2003/08/03 15:03
2	BRS	L3	108799	257/\$.ccls. (substrate with insulat\$3 with conductive with semi\$1conductor)	USPAT	2003/08/03 15:05
3	BRS	L4	108490	257/\$.ccls. (substrate with insulating with conductive with semi\$1conductor)	USPAT	2003/08/03 15:06
4	BRS	L5	107809	257/\$.ccls. ((insulating adj substrate) with (conductive adj substrate))	USPAT	2003/08/03 15:08
5	BRS	L1	5739	substrate with insulat\$3 with conductive with semi\$1conductor	USPAT	2003/08/03 15:13
6	BRS	L6	175	(insulating adj substrate) with (conductive adj substrate)	USPAT	2003/08/03 15:40
7	IS&R	L7	2	("5753911").PN.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/08/03 15:42
8	BRS	L14	801	257/\$.ccls. and (silicon adj electrode)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/08/03 15:44
9	BRS	L21	583	257/\$.ccls. and (silicon adj electrode)	USPAT	2003/08/03 15:46
10	BRS	L22	1556	257/\$.ccls. and (SOI adj substrate)	USPAT	2003/08/03 15:51

	Comments	Error Definition	Errors
1			0
2			0
3			0
4			0
5			0
6			0
7			0
8			0
9			0
10			0

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